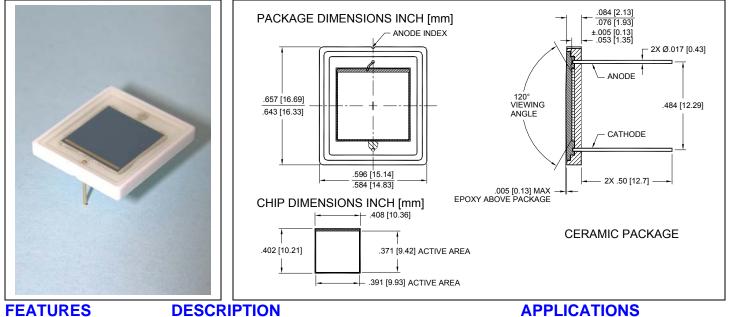


Blue Enhanced Photoconductive Silicon Photodiode PDB-C110



Low noise

The PDB-C110 is a blue enhanced PIN silicon

- photodiode in a photoconductive mode, packaged in a ceramic package.
- High shunt resistance

Blue enhanced

High response

ABSOLUTE MAXIMUM RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	PARAMETER	MIN	MAX	UNITS
V _{BR}	Reverse Voltage		75	V
T _{STG}	Storage Temperature	-20	+80	°C
To	Operating Temperature	-20	+60	°C
Ts	Soldering Temperature*		+240	°C

* 1/16 inch from case for 3 seconds max.

ELECTRO-OPTICAL CHARACTERISTICS RATING (TA)= 23°C UNLESS OTHERWISE NOTED

SYMBOL	CHARACTERISTIC	TEST CONDITIONS	MIN	ТҮР	MAX	UNITS
I _{SC}	Short Circuit Current	H = 100 fc, 2850 K	1.0	1.3		mA
I _D	Dark Current	V _R = 10V		10	30	nA
R _{SH}	Shunt Resistance	V _R = 10 mV	15	30		MΩ
CJ	Junction Capacitance	V _R =10 V, <i>f</i> = 1 MHz		300		pF
λ range	Spectral Application Range	Spot Scan	350		1100	nm
R	Responsivity	λ = 450 nm V, V _R = 0 V	0.15	0.17		A/W
V _{BR}	Breakdown Voltage	I = 10 μA	30	50		V
NEP	Noise Equivalent Power	V_{R} = 0V @ λ = Peak		3x10 ⁻¹³		W/ $\sqrt{_{\rm Hz}}$
tr	Response Time**	RL = 50 Ω, V _R = 0 V		190		nS
		RL = 50 Ω, V _R = 10 V		13		

**Response time of 10% to 90% is specified at 660nm wavelength light.

Information in this technical datasheet is believed to be correct and reliable. However, no responsibility is assumed for possible inaccuracies or omission. Specifications are subject to change without notice.

Instrumentation

- Industrial
- Medical

SPECTRAL RESPONSE

